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#### SCES309F-DECEMBER 2001-REVISED DECEMBER 2013

# Dual Positive-Edge-Triggered D-Type Flip-Flop

Check for Samples: SN74LVC2G80

### **FEATURES**

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V •
- Max  $t_{pd}$  of 4.2 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- Typical V<sub>OLP</sub> (Output Ground Bounce) . <0.8 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Ioff Feature Supports Live Insertion, Partial-**Power-Down and Back Drive Protection** Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22

1CLK

1D [

20 [ 

GND [

- 2000-V Human-Body Model (A114-A)
- 200-V Machine Model (A115-A)
- 1000-V Charged-Device Model (C101)

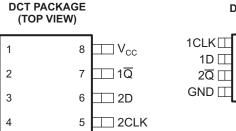


This dual positive-edge-triggered D-type flip-flop is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

When data at the data (D) input meets the setup time requirement, the data is transferred to the  $\overline{Q}$  output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}.$  The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



See mechanical drawings for dimensions.

[		PACKAGE P VIEW)	1
CLK□	1	8	□ V <sub>cc</sub>
1D 🖂	2	7	∐ 1 <u>Q</u>
2 <u>Q</u> []	3	6	∐ 2D
ND 🖂	4	5	1 2CLK

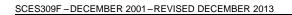
YZP	PACK	٩GE
•	TOM V	,
GND	O4 50	2CLK

GND	O4 50	2CLK
2Q	O36O	2D
1D	0270	1Q
1CLK	0180	V <sub>cc</sub>



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

## SN74LVC2G80



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**STRUMENTS** 

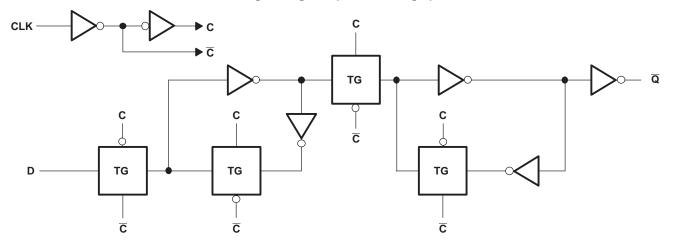
XAS



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

	unction Each Flip	
INPU	JTS	OUTPUT
CLK	D	Q
1	Н	L
↑	L	н
L	Х	Q <sub>0</sub>

#### Logic Diagram (Positive Logic)



### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Output voltage range <sup>(2)</sup> <sup>(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through $V_{\mbox{\scriptsize CC}}$ or GND			±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
		YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.



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## **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.65	5.5	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		v
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
V	Lligh lovel input veltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		V
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		v
		$V_{CC}$ = 4.5 V to 5.5 V	$0.7 \times V_{CC}$		
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	
V		$V_{CC}$ = 2.3 V to 2.7 V		0.7	V
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V$ to 3.6 V		0.8	v
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$		$0.3 \times V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		V <sub>CC</sub> = 2.3 V		-8	
I <sub>OH</sub>	High-level output current	$V_{CC} = 3 V$		-16	mA
		VCC = 3 V		-24	
		$V_{CC} = 4.5 V$		-32	
		V <sub>CC</sub> = 1.65 V		4	
		V <sub>CC</sub> = 2.3 V		8	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3 V$		16	mA
		$v_{CC} = 3 v$		24	
		$V_{CC} = 4.5 V$		32	
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. SCES309F-DECEMBER 2001-REVISED DECEMBER 2013

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### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS		-40°	C to 85°C		-40°0	C to 125°C		
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	MIN	TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> – 0.1			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			1.2			
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.9			v
V <sub>он</sub>	$I_{OH} = -16 \text{ mA}$	2.14	2.4			2.4			v
	$I_{OH} = -24 \text{ mA}$	3 V	2.3			2.3			
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8			3.8			
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V			0.1			0.1	
	I <sub>OL</sub> = 4 mA	1.65 V			0.45			0.45	1
	I <sub>OL</sub> = 8 mA	2.3 V			0.3			0.3	v
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	0.14			0.4			0.4	v
	I <sub>OL</sub> = 24 mA	3 V			0.55			0.65	
	I <sub>OL</sub> = 32 mA	4.5 V			0.55			0.65	
I <sub>I</sub> D input	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±1			±1	μA
l <sub>off</sub>	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0			±1			±10	μA
I <sub>cc</sub>	$V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$	1.65 V to 5.5 V			5			5	μA
ΔI <sub>CC</sub>	One input at $V_{CC} - 0.6 V$ , Other inputs at $V_{CC}$ or GND	3 V to 5.5 V			500			500	μA
Ci	$V_{I} = V_{CC}$ or GND	0		3.5					pF

(1) All typical values are at V<sub>CC</sub> = 3.3 V,  $T_A$  = 25°C.

### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

						SN74LV -40°C t					
			V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5.5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			160		160		160		160	MHz
tw	Pulse duration, CLK high or low		2.5		2.5		2.5		2.5		ns
	Catur time before CLKA	Data high	2.2		1.4		1.1		0.9		20
ι <sub>su</sub>	Setup time before CLK↑	Data low	2.2		1.4		1.1		0.9		ns
t <sub>h</sub>	Hold time, data after CLK↑		1.6		1		0.8		0.6		ns

### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

						SN74LV -40°C to					
			V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5.5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			160		160		160		160	MHz
t <sub>w</sub>	Pulse duration, CLK high or low		2.5		2.5		2.5		2.5		ns
	Satur time before CLKA	Data high	2.2		1.4		1.1		0.9		
ι <sub>su</sub>	Setup time before CLK↑	Data low	2.2		1.4		1.1		0.9		ns
t <sub>h</sub>	Hold time, data after CLK↑		1.6		1		0.8		0.6		ns



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### Switching Characteristics

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER						SN74LV -40°C t					
	FROM (INPUT)	TO (OUTPUT)		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		3.3 V 5 V	V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			160		160		160		160		MHz
t <sub>pd</sub>	CLK	Q	3	9.1	1.5	6	1.3	4.2	1.1	3.8	ns

### **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER						SN74LV -40°C t						
	ARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	f <sub>max</sub>			160		160		160		160		MHz
	t <sub>pd</sub>	CLK	Q	3.8	13.9	1.5	7	1.4	5.2	0.9	4.5	ns

### **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

						SN74LV -40°C to					
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			160		160		160		160		MHz
t <sub>pd</sub>	CLK	Q	3.8	14.5	1.5	7.5	1.4	5.8	0.9	5	ns

### **Operating Characteristics**

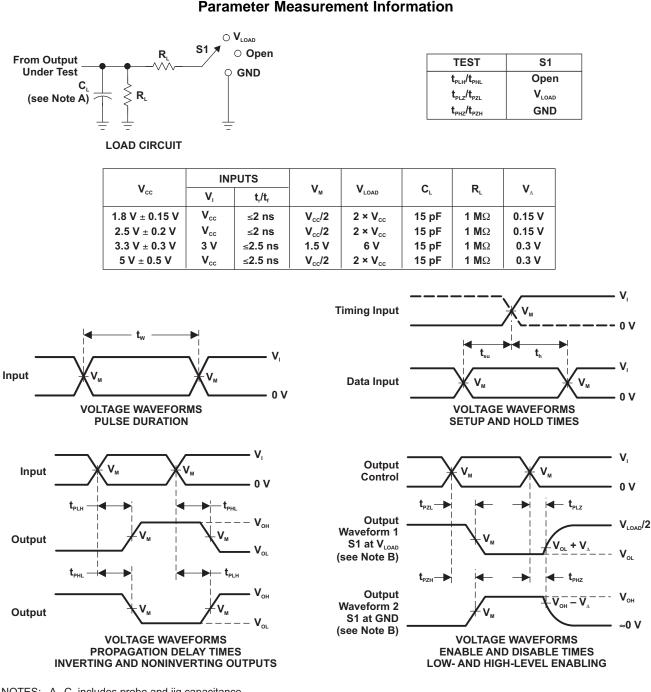
 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT
	FARAIVIETER	TEST CONDITIONS	TYP	TYP	ТҮР	ТҮР	UNIT
C	C <sub>pd</sub> Power dissipation capacitance	f = 10 MHz	21	21	22	25	pF

### EXAS **NSTRUMENTS**

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NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{\mbox{\tiny PLH}}$  and  $t_{\mbox{\tiny PHL}}$  are the same as  $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms

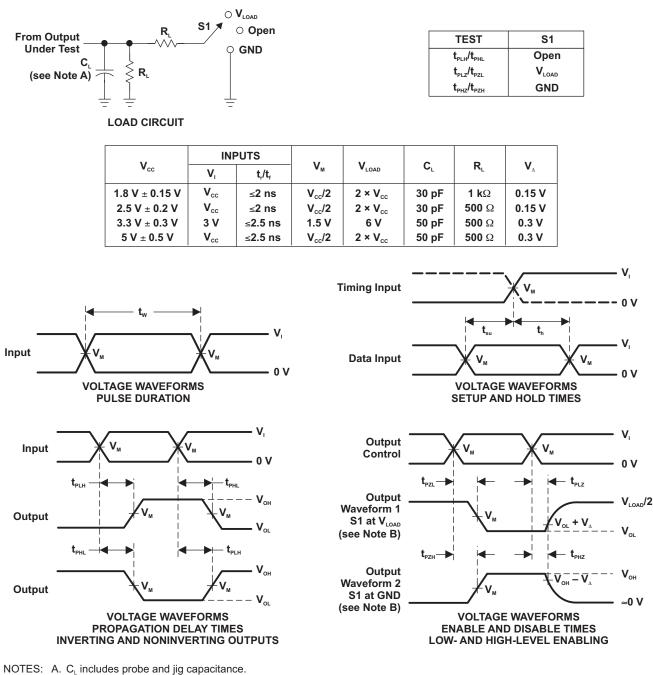


## SN74LVC2G80

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#### Parameter Measurement Information



B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ .

- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{\mbox{\tiny PLH}}$  and  $t_{\mbox{\tiny PHL}}$  are the same as  $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 2. Load Circuit and Voltage Waveforms

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# **REVISION HISTORY**

## Changes from Revision E (Feburary 2007 ) to Revision F

Updated operating temperature range. ..... 3

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12-Sep-2016

### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC2G80DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C80 Z	Samples
SN74LVC2G80DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C80 Z	Samples
SN74LVC2G80DCUR	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 125	(C80Q ~ C80R)	Samples
SN74LVC2G80DCURG4	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C80R	Samples
SN74LVC2G80YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CXN	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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# PACKAGE OPTION ADDENDUM

12-Sep-2016

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G80DCTR	SM8	DCT	8	3000	180.0	13.0	3.35	4.5	1.55	4.0	12.0	Q3
SN74LVC2G80DCUR	VSSOP	DCU	8	3000	178.0	9.5	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G80DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G80DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G80YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

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# PACKAGE MATERIALS INFORMATION

28-Sep-2017



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G80DCTR	SM8	DCT	8	3000	182.0	182.0	20.0
SN74LVC2G80DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G80DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G80DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G80YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.





- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

#### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



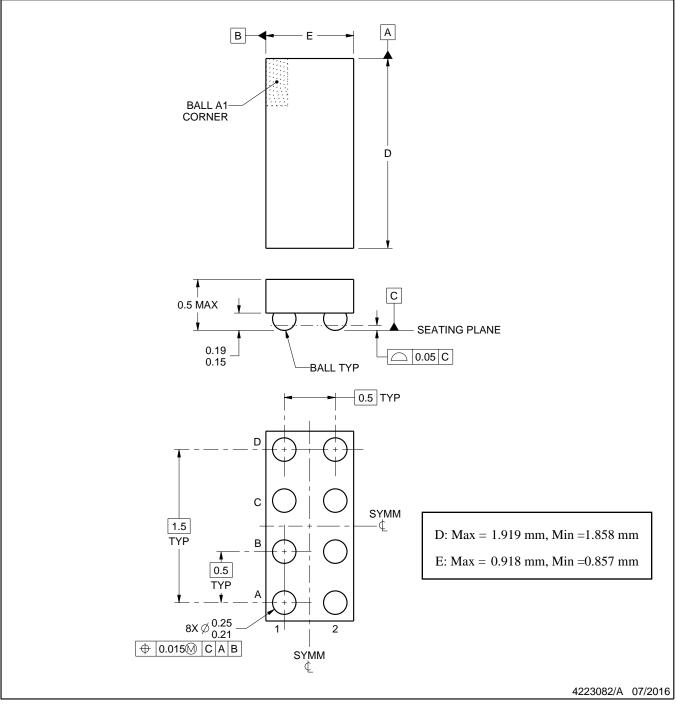
# YZP0008



# **PACKAGE OUTLINE**

## DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



# YZP0008

# **EXAMPLE BOARD LAYOUT**

## DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



# YZP0008

# **EXAMPLE STENCIL DESIGN**

## DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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